

## ULTRA FAST RECOVERY RECTIFIER DIODES



Glass-passivated, high-efficiency epitaxial rectifier diodes in DO-4 metal envelopes, featuring low forward voltage drop, ultra fast reverse recovery times, very low stored charge and soft recovery characteristic. They are intended for use in switched-mode power supplies and high-frequency circuits in general, where low conduction and switching losses are essential. The series consists of normal polarity (cathode to stud) types.

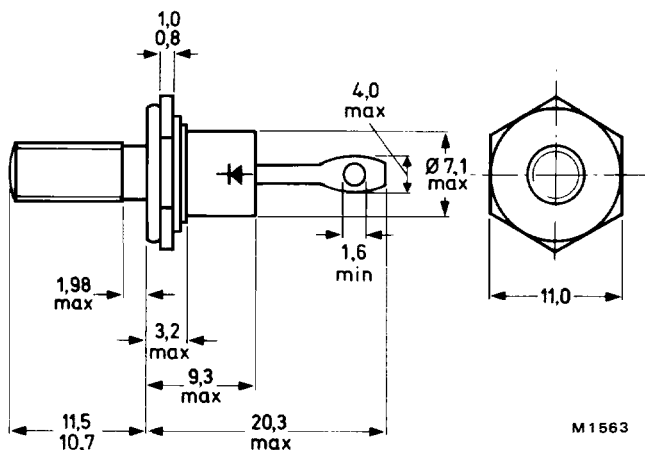
## QUICK REFERENCE DATA

|                                 |             | BYW30-50 |     |     |     |     |    |
|---------------------------------|-------------|----------|-----|-----|-----|-----|----|
|                                 |             |          | 100 | 150 | 200 |     |    |
| Repetitive peak reverse voltage | $V_{RRM}$   | max.     | 50  | 100 | 150 | 200 | V  |
| Average forward current         | $I_{F(AV)}$ | max.     | 14  |     |     |     | A  |
| Forward voltage                 | $V_F$       | <        | 0.8 |     |     |     | V  |
| Reverse recovery time           | $t_{rr}$    | <        | 30  |     |     |     | ns |

## MECHANICAL DATA

Dimensions in mm

Fig.1 DO-4: with metric M5 stud ( $\phi 5$  mm); e.g. BYW30-50.  
with 10-32 UNF stud ( $\phi 4.83$  mm); e.g. BYW30-50U.



Net mass: 6 g

Diameter of clearance hole: max. 5.2 mm

Accessories supplied on request:  
see ACCESSORIES section.

Supplied with device: 1 nut, 1 lock washer

Torque on nut: min. 0.9 Nm (9 kg cm)  
max. 1.7 Nm (17 kg cm)

Nut dimensions across the flats:  
M5: 8.0 mm; 10-32 UNF: 9.5 mm.



Products approved to CECC 50 009-001, available on request.

# RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

| Voltages*                       |           | BYW30-50 | 100 | 150 | 200 |   |
|---------------------------------|-----------|----------|-----|-----|-----|---|
| Repetitive peak reverse voltage | $V_{RRM}$ | max. 50  | 100 | 150 | 200 | V |
| Crest working reverse voltage   | $V_{RWM}$ | max. 50  | 100 | 150 | 200 | V |
| Continuous reverse voltage      | $V_R$     | max. 50  | 100 | 150 | 200 | V |

# Currents

|                                                                            |              |      |      |                      |  |
|----------------------------------------------------------------------------|--------------|------|------|----------------------|--|
| Average forward current; switching losses negligible up to 500 kHz         |              |      |      |                      |  |
| square wave; $\delta = 0.5$ ; up to $T_{mb} = 120\text{ }^{\circ}\text{C}$ | $I_{F(AV)}$  | max. | 14   | A                    |  |
| up to $T_{mb} = 125\text{ }^{\circ}\text{C}$                               | $I_{F(AV)}$  | max. | 12   | A                    |  |
| sinusoidal; up to $T_{mb} = 125\text{ }^{\circ}\text{C}$                   | $I_{F(AV)}$  | max. | 12.5 | A                    |  |
| R.M.S. forward current                                                     | $I_{F(RMS)}$ | max. | 20   | A                    |  |
| Repetitive peak forward current                                            |              |      |      |                      |  |
| $t_p = 20\text{ }\mu\text{s}$ ; $\delta = 0.02$                            | $I_{FRM}$    | max. | 420  | A                    |  |
| Non-repetitive peak forward current                                        |              |      |      |                      |  |
| half sine-wave; $T_j = 150\text{ }^{\circ}\text{C}$ prior to surge;        |              |      |      |                      |  |
| with reapplied $V_{RWMmax}$ ;                                              |              |      |      |                      |  |
| $t = 10\text{ ms}$                                                         | $I_{FSM}$    | max. | 200  | A                    |  |
| $t = 8.3\text{ ms}$                                                        | $I_{FSM}$    | max. | 240  | A                    |  |
| $I^2t$ for fusing ( $t = 10\text{ ms}$ )                                   | $I^2t$       | max. | 200  | $\text{A}^2\text{s}$ |  |

# Temperatures

|                      |           |             |                  |
|----------------------|-----------|-------------|------------------|
| Storage temperature  | $T_{stg}$ | -55 to +150 | $^\circ\text{C}$ |
| Junction temperature | $T_j$     | max. 150    | $^\circ\text{C}$ |

# THERMAL RESISTANCE

|                                                 |               |   |     |     |
|-------------------------------------------------|---------------|---|-----|-----|
| From junction to mounting base                  | $R_{th j-mb}$ | = | 2.2 | K/W |
| From mounting base to heatsink                  |               |   |     |     |
| a. with heatsink compound                       | $R_{th mb-h}$ | = | 0.5 | K/W |
| b. without heatsink compound                    | $R_{th mb-h}$ | = | 0.6 | K/W |
| Transient thermal impedance; $t = 1 \text{ ms}$ | $Z_{th j-mb}$ | = | 0.3 | K/W |

# MOUNTING INSTRUCTIONS

The top connector should be neither bent nor twisted; it should be soldered into the circuit so that there is no strain on it.

During soldering the heat conduction to the junction should be kept to a minimum.

\*To ensure thermal stability:  $R_{th j-a} \leq 5.6 \text{ K/W}$  (continuous reverse voltage).

## CHARACTERISTICS

## Forward voltage

$$I_F = 15 \text{ A}; T_j = 150 \text{ }^{\circ}\text{C}$$

$$I_F = 50 \text{ A}; T_j = 25 \text{ }^{\circ}\text{C}$$

|       |   |     |       |
|-------|---|-----|-------|
| $V_F$ | < | 0.8 | $V^*$ |
| $V_F$ | < | 1.3 | $V^*$ |

## Reverse current

$$V_R = V_{RWM} \text{ max}; T_j = 100 \text{ }^{\circ}\text{C}$$

$$T_j = 25 \text{ }^{\circ}\text{C}$$

|       |   |     |               |
|-------|---|-----|---------------|
| $I_R$ | < | 1.3 | mA            |
| $I_R$ | < | 25  | $\mu\text{A}$ |

## Reverse recovery when switched from

$$I_F = 1 \text{ A to } V_R \geq 30 \text{ V with } -dI_F/dt = 100 \text{ A}/\mu\text{s};$$

$$T_j = 25 \text{ }^{\circ}\text{C}; \text{ recovery time}$$

|          |   |    |    |
|----------|---|----|----|
| $t_{rr}$ | < | 30 | ns |
|----------|---|----|----|

$$I_F = 2 \text{ A to } V_R \geq 30 \text{ V with } -dI_F/dt = 20 \text{ A}/\mu\text{s};$$

$$T_j = 25 \text{ }^{\circ}\text{C}; \text{ recovered charge}$$

|       |   |    |    |
|-------|---|----|----|
| $Q_s$ | < | 15 | nC |
|-------|---|----|----|

$$I_F = 10 \text{ A to } V_R \geq 30 \text{ V with } -dI_F/dt = 50 \text{ A}/\mu\text{s};$$

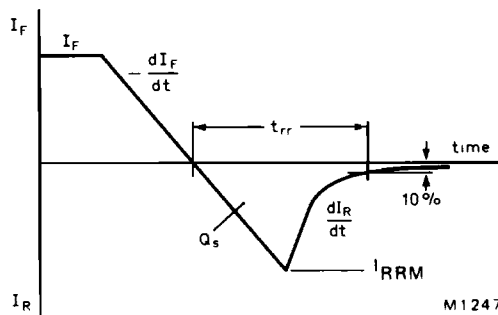
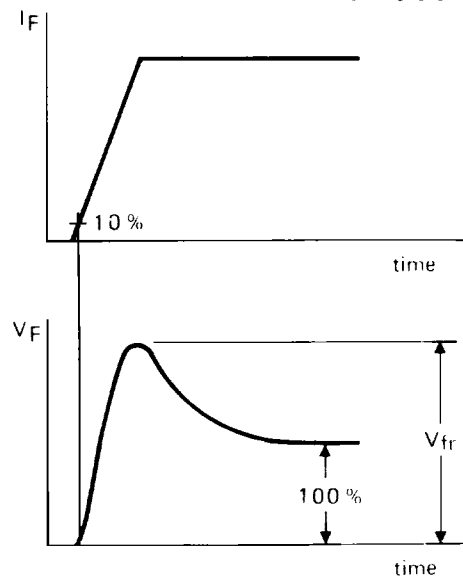
$$T_j = 100 \text{ }^{\circ}\text{C}; \text{ peak recovery current}$$

|           |   |   |   |
|-----------|---|---|---|
| $I_{RRM}$ | < | 4 | A |
|-----------|---|---|---|

Forward recovery when switched to  $I_F = 10 \text{ A}$ 

$$\text{with } dI_F/dt = 10 \text{ A}/\mu\text{s}; T_j = 25 \text{ }^{\circ}\text{C}$$

|          |      |     |   |
|----------|------|-----|---|
| $V_{fr}$ | typ. | 1.0 | V |
|----------|------|-----|---|

Fig.2 Definition of  $t_{rr}$ ,  $Q_s$  and  $I_{RRM}$ .Fig.3 Definition of  $V_{fr}$ .

\*Measured under pulse conditions to avoid excessive dissipation.

SQUARE-WAVE OPERATION

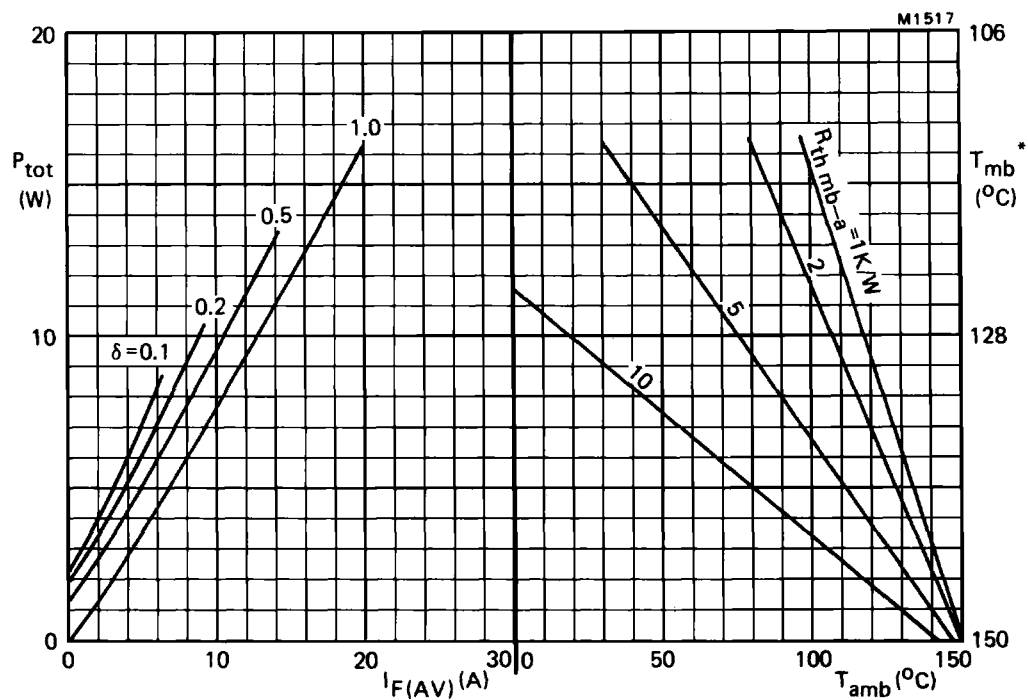
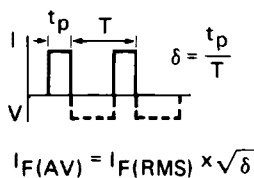


Fig.4 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures. Power includes reverse current losses and switching losses up to  $f = 500$  kHz.



\* $T_{mb}$  scale is for comparison purposes and is correct only for  $R_{th\ mb-a} < 3.1$  K/W.

## SINUSOIDAL OPERATION

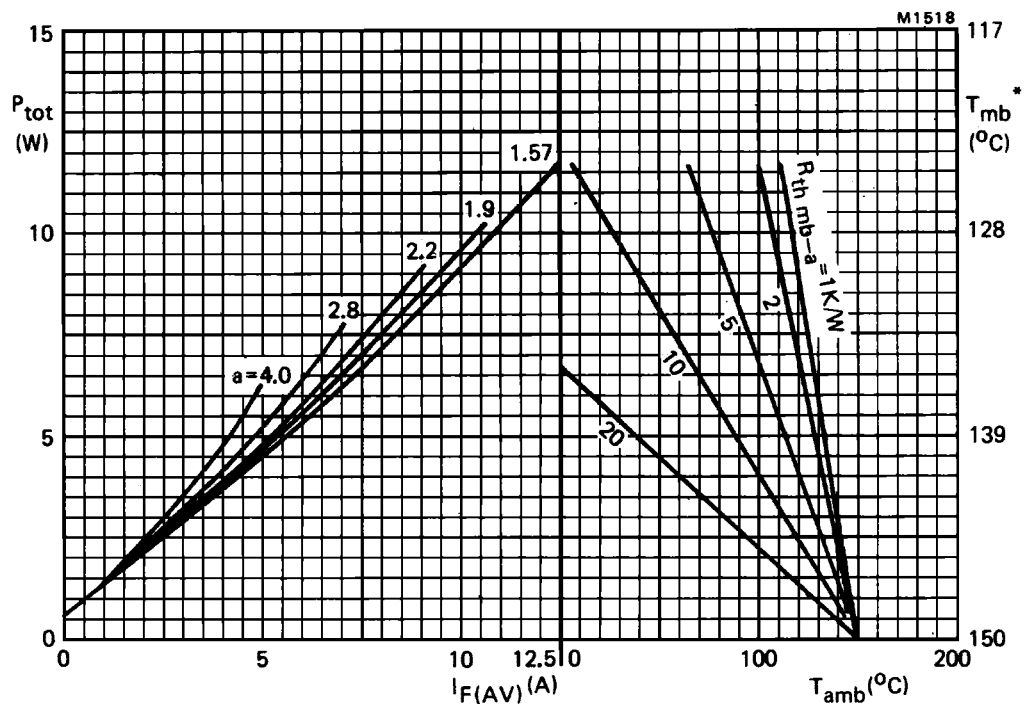


Fig.5 The right-hand part shows the interrelationship between the power (derived from the left-hand part) and the maximum permissible temperatures.

$a$  = form factor =  $I_F(\text{RMS})/I_F(\text{AV})$ .

\* $T_{mb}$  scale is for comparison purposes and is correct only for  $R_{th\ mb-a} < 17\ \text{K/W}$ .

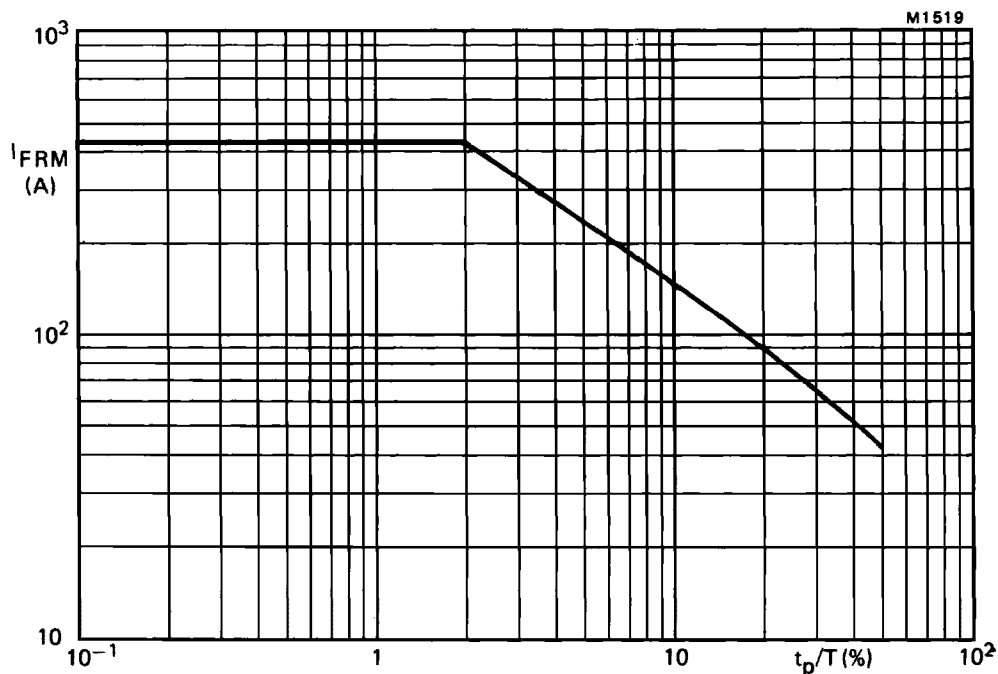
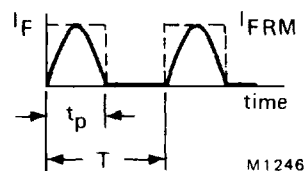
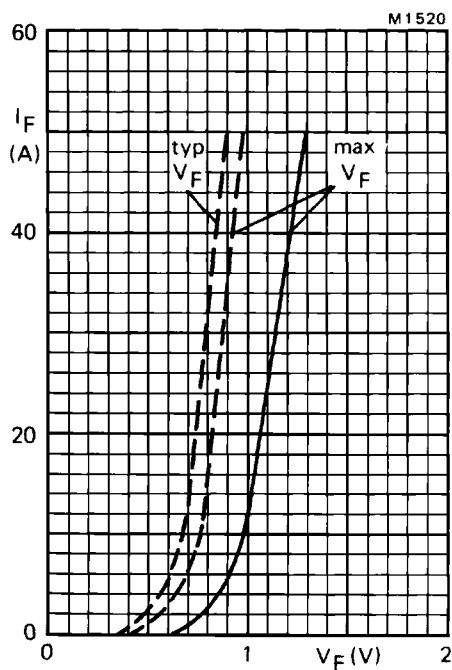
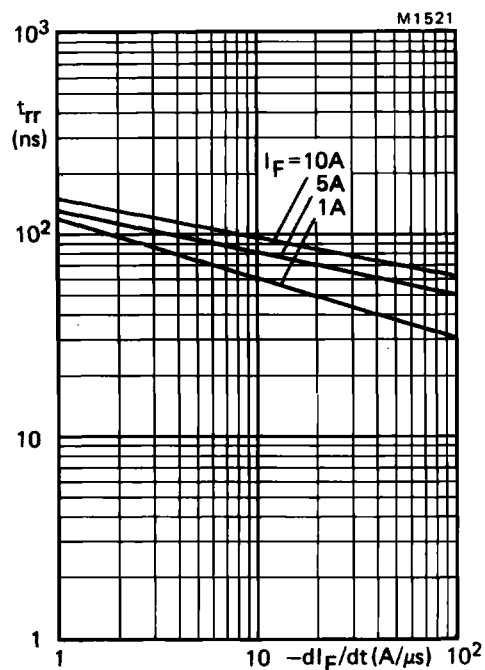
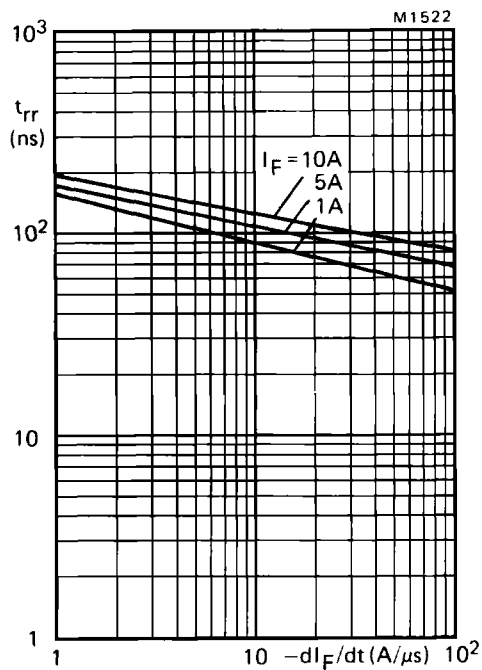
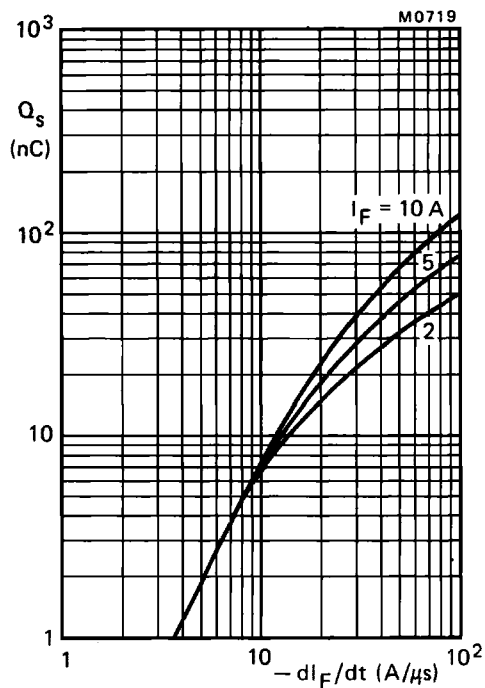


Fig.6 Maximum permissible repetitive peak forward current for square or sinusoidal currents;  
 $\mu s < t_p < 1$  ms.



Definition of  $I_{FRM}$   
 and  $t_p/T$ .

Fig.7 —  $T_j = 25$  °C; ---  $T_j = 150$  °C.

Fig.8 Maximum  $t_{rr}$  at  $T_j = 25\text{ }^{\circ}\text{C}$ .Fig.9 Maximum  $t_{rr}$  at  $T_j = 100\text{ }^{\circ}\text{C}$ .Fig.10 Maximum  $Q_s$  at  $T_j = 25\text{ }^{\circ}\text{C}$ .

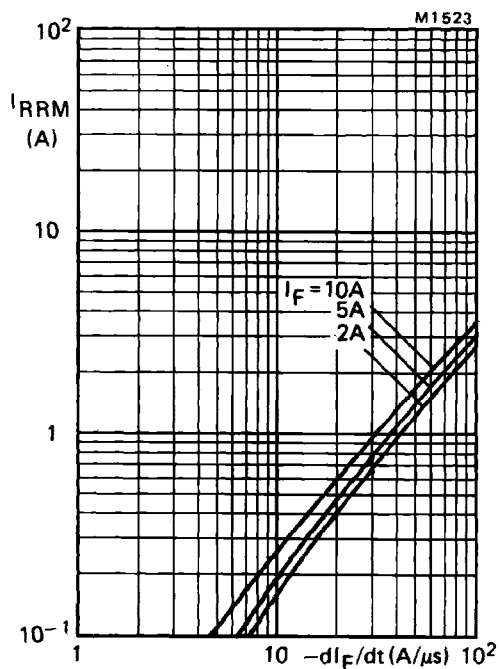


Fig.11 Maximum  $I_{RRM}$  at  $T_j = 25^\circ\text{C}$ .

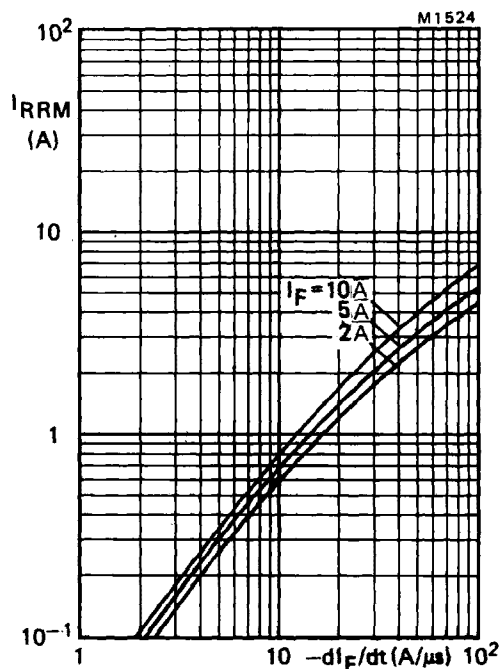


Fig.12 Maximum  $I_{RRM}$  at  $T_j = 100^\circ\text{C}$ .

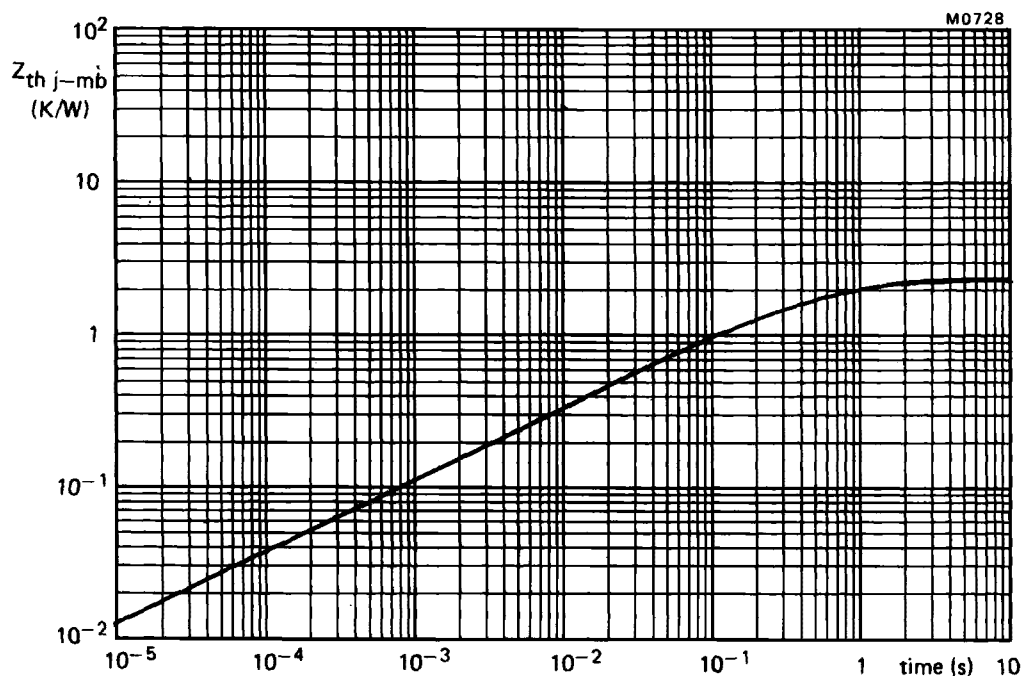


Fig.13 Transient thermal impedance.